TOSHIBA GaAs Linear Integrated Circuit GaAs Monolithic

TG2401F

1.9 GHz Band TX Fronted IC

PHS, Digital Cordless Telecommunication

Features

Common Block

• Positive voltage operation: $V_{DD1} = V_{DD2} = 3.0 V$,

 $V_{DD3} = V_{DD4} = 3.6 V$

- Small package: HSOP20 (0.5 mm pin pitch)
- Power Amp. Block
- High power Gain: G_p = 32dB (min)

Antenna Switch Block

- Low insertion Loss: LOSS = 0.8dB (typ.)
- High isolation: ISL = 25dB (typ.)

Maximum Ratings (Ta = 25°C)



Weight: 0.058 g (typ.)

Characteristics	Symbol	Rating	Unit
	V _{DD} (Note 1)	5	V
Supply voltage	V _{GG} (Note 2)	4	V
	V _C (Note 3)	3.65	V
Input power	Pi	1	mW
Power dissipation	P _d (Note 4)	4	W
Operating temperature range	T _{opr} (Note 5)	-40 to 85	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note 1: $V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = V_{DD}$ (SW)

- Note 2: $V_{GG} = V_{GG3} = V_{GG4}$
- Note 3: $V_{C} = V_{C1} = V_{C2}$
- Note 4: When mounted on a Teflon board (52 mm \times 43 mm \times 0.4 mm) that is fixed to an aluminum plate. (Ta = 25°C)
- Note 5: Not intended to guarantee the following electrical characteristics, which were measured at $Ta = 25^{\circ}C$.

Caution

This device is electrostatic sensitivity. Please handle with caution.

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Electrical Characteristics

[Power Amp, Block]

$(V_{DD} = V_{DD2} = 3 V, V_{DD3} = V_{DD4} = 3.6 V, V_{GG} = (Note6), f = 1.893 GHz, Ta = 25^{\circ}C, Zg = ZI = 50^{\circ}C$)Ω)
[ANT-SW Block]	

$(V_{DD (SW)} = 3 V, f = 1.893 GHz, Ta = 25°C)$

Characteristics	Symbol	Test Circuit	Test Condition		Min	Тур.	Max	Unit
Operating frequency	f	_	—		1.893		1.920	GHz
Supply current (PA)	l _t	_	P _o = 20.5dBmW, P _i = adjust				170	mA
Gate current (PA)	I _{GG}	_	$V_{GG} = 2 V$				2	mA
Power gain	Gp		$P_0 = 20.5 dBmW$		32	_	38	dB
Output deviation	ΔP_{O}	_	f = 1.893,1.920 GHz, P _i =fixed			0.5	1.0	dB
Input VSWR	VSWRin	_	$P_i = -30 dBmW$				3.0	_
Adjagant abannal laakaga pawar ratia	ACP (1)	_	$P_0 = 20.5 dBmW$,	$\Delta f = 600 \text{ kHz}$			-55	dB
Aujacent channel leakage power ratio	ACP (2)		P _i = adjust	$\Delta f = 900 \text{ kHz}$		_	-60	dB
Hermonico	2f0						-30	dB
Harmonics	3f0		$P_0 = 20.500000000000000000000000000000000000$	P _i = adjust			-30	dB
Load mismatch		_	$\begin{array}{l} V_{DD3,\;4}=4.2\;V,\;V_{GG}=adjust,\\ P_{o}=20.5dBmW,\;P_{i}=adjust,\\ Zg=50\;\Omega\\ VSWR\;Load=6:1\;all\;phase \end{array}$				tion	_
Stability		_	$\begin{array}{l} V_{DD3, \ 4} = 3.2 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$		$\begin{array}{l} V_{DD3,\;4}=3.24.2\;\text{V},\\ V_{C1}=3\;\text{V},\;V_{GG}=\text{adjust},\\ P_i=-15\text{dBmW}\;\text{to}-10\text{dBmW},\\ Zg=50\;\Omega\\ \text{VSWR}\;\text{Load}=6\text{:1}\;\text{all phase} \end{array} \qquad $		JS	
Supply current (SW)	I _{DD}	ΤХ	$V_{C1} = 3 V, V_{C2} =$	0 V	_	_	0.04	mA
		RX	$V_{C1} = 0 V, V_{C2} = 0$	3 V	_		0.04	mA
Control current (SW)	I _{rx}	ТΧ	$V_{C1} = 3 V, V_{C2} = 0 V$				0.04	mA
	I _{tx}	RX	$V_{C1} = 0 V, V_{C2} = 3 V$				0.04	mA
Insertion Loss	L _{OSS}	RX	$\label{eq:VC1} \begin{array}{l} V_{C1} = 0 \; V, V_{C2} = 3 \; V, \\ P_i \; (SW) = 0 dB m W \end{array}$			0.8	1.0	dB
Isolation	ISL	тх	$V_{C1} = 3 V, V_{C2} = 0 V,$ $P_{O} = 20.5 dBmW$		20	25		dB
		RX	$V_{C1} = 0 V, V_{C2} = P_i (SW) = 0 dBmW$	3 V,	10	15	_	dB

(1) The P_0 in this technical data includes insertion Loss for ANT-SW.

(2) Stability's load condition is that SHORT STAB join to ANT (Pin No.11) and all phase.

(3) All test for ELCTRICAL CHARACTERISTICS bases on measure with following "RF TES BOARD".

(4) Control current is separated by TX and RX mode. TX control current is I_{rx} , RX control current is I_{tx} .

(5) Operation mode

	RX Mode	TX Mode
VC1	$0\pm0.2\;V$	$\begin{array}{c} 3+0.4 \ V \\ 3-0.2 \ V \end{array}$
V _{C2}	$\begin{array}{c} 3 + 0.4 \ V \\ 3 - 0.2 \ V \end{array}$	$0\pm0.2\;V$

 $V_{DD (SW)} = 3 \pm 0.05 V$

(6) Input signal is modulated to $\pi/4$ QPSK ($\alpha = 0.5$). Bit rate is 384 kbps.

(7) 1/2 duty operation.

Note 6: Classify VGG Rank (UNDECIDED)

Rank	V _{GG} Condition
000	0 V
010	1 V
020	2 V
030	2.8 V

Pin Assignment (top view)



Rank Indication Example)

0 1

V_{GG} input voltage: 1.0 V

Marking

Classify customer: standard products 0

Caution

10000 pF

10000 pF

2 pF

100 pF

9 pF

The circuits and measurements contained in this document are given only in the context of as examples of applications for these products.

т,

V_{C1}

GND

ANT

Moreover, these example application circuits are not intended for mass production, since the high-frequency characteristics (the AC characteristics) of these devices will be affected by the external components which the customer uses, by the design of the circuit and by various other conditions.

It is the responsibility of the customer to design external circuits which correctly implement the intended application, and to check the characteristics of the design.

TOSHIBA assume no responsibility for the integrity of customer circuit designs or applications.

V_{DD} (SW)

 R_{x}

GND

V_{C2}

100 pF

<u></u> 10000 pF

9 pl

9 pF

100 pF主

10000 pF

Curve Data



	Gp (dB)
	It (mA)
	ACP (dB)
	2f0 (dB)
	3f0 (dB)

 G_p , ACP, 2f0, 3f0 - V_{DD} 34 VDD12 = 3 V, VDD34 = 3.6 V, Po = 20.5dBmW, f = 1920 MHz 40 10 (dB) ←GF 36 -20 h 3f0 -30 2f0, 32 40 (dB) ACP, • • • ... -50 •••• പ്പ **...** 28 -60 Gp (dB) 130 -- It (mA) _ _ 24 125 (W 125 I ····· ACP (dB) ----- 2f0 (dB) – – 3f0 (dB) 20L 2.8 120 3 3.2 3.4 3.6 3.8 V_{DD}34 (V)



RF Test Board



TG2401F

Package Dimensions

HSOP20-P-225-0.50

Unit: mm



Weight: 0.058 g (typ.)

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Handbook" etc.,

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